

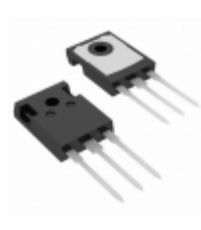

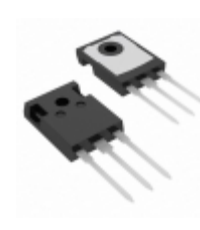
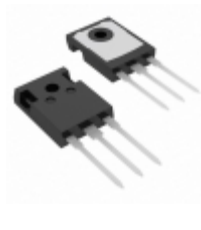
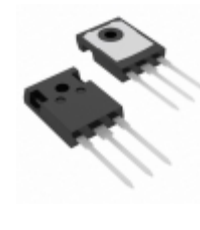
	<h2 style="color: red;">FQH8N100C</h2>
	<p>Hersteller-Teilenummer: FQH8N100C</p> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 1000V 8A TO-247</p> <p>Datenblätter:  FQH8N100C.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 12161 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQH8N100C
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 1000V 8A TO-247
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	12161 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-247-3
Supplier Device-Gehäuse	TO-247
Verlustleistung (max)	225W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	1000V (1kV)
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	8A (Tc)
Rds On (Max) @ Id, Vgs	1.45 Ohm @ 4A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	70nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	3220pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Tube

FQH8N100C ist neu im Original, Suche FQH8N100C Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQH8N100C Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQH8N100C: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQH8N100C AMI Semiconductor / ON Semiconductor MOSFET N-CH 1000V 8A TO-247</p>	 <p>FQH70N10 Fairchild/ON Semiconductor MOSFET N-CH 100V 70A TO-247</p>	 <p>FQH70N15 FSC FQH70N15 FSC</p>	 <p>FQH44N10_F133 Fairchild/ON Semiconductor FQH44N10_F133 Fairchild/ON Semiconductor</p>
 <p>FQH44N10-F133 AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 48A TO-247</p>	 <p>FQH90N15 Fairchild/ON Semiconductor MOSFET N-CH 150V 90A TO-247</p>	 <p>FQH44N10 Fairchild/ON Semiconductor MOSFET N-CH 100V 48A TO-247</p>	 <p>FQH44N10 AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 48A TO-247</p>

heiße Teile

Mehr

12105C474KAT9A	1503PA50	251-003/K010-1910/000-200	D 2DI30Z-120(A)	AAT3562IGY-2.20-T1
ACH3218-682-TD01	ADF7022BCPZ	D AP3N045EN-HF	AR1200-S85QEGK0	C2012CH2W181J060AA
CDRH4D28-2R2NC	CL03C1R2BA3GNNC	CL10C241JB8NNNC	DDTC113TE-7-F	EMZC6.8N
D FA1113F-TR	FP50R12KS4	FQH44N10	FQH44N10	FQH44N10_F133
FQH70N15	FQH8N100C	FQI13N06	GRM0225C1E9R0WDAEL	GRM0335C2A4R1CA01J
GRM1555C1HR75CA01J	GRM2196S2A130JZ01D	D ISPLSI2064E-100LT100	LC4032ZC-75TN	LFB321G07SA1A606
LQP03TN3N9B00D	D LT1085CT-5.0	LTC1046CS8#TRPBF	M63820KP	MAX202CSE+T
MCP6032-E/SN	MDF18N50	MT49H32M18FM-25E:B	NCP717CMX310TCG	PBLS6001D
PDTC144ES	PK55F160	PRZ0908V15PP5U	D STV0984NP/TR	SUP85N04-03-E3
T3101N16TOF	V24C5C100B3	VE-J04-MZ	VI-2N1-EU	VS-48CTQ060STRLPBF

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